

# CSD19532Q5B

### CSD19532Q5B Information





Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## CSD19532Q5B Specifications

Manufacturer Part Number	CSD19532Q5B
Manufacturer	Texas Instruments
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	NexFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	100A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4810pF @ 50V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	3.1W (Ta), 195W (Tc)
Rds On (Max) @ Id, Vgs	4.9 mOhm @ 17A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-VSON (5x6)
Package / Case	8-PowerTDFN
	Report errors?

#### CSD19532Q5B Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### CSD19532Q5B Payment Methods





If you have any question about CSD19532Q5B, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com